
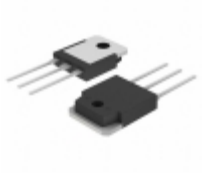
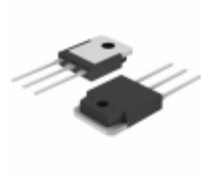
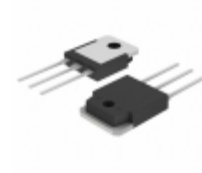
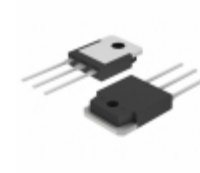

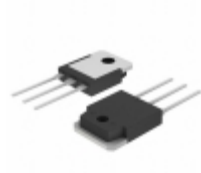

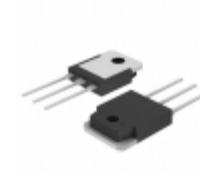
	<h2 style="color: red;">FQA55N10</h2>
	<p>Hersteller-Teilenummer: FQA55N10</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 100V 61A TO-3P</p> <hr/> <p>Datenblätter:  FQA55N10.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 6427 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQA55N10
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 100V 61A TO-3P
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	6427 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-3P-3, SC-65-3
Supplier Device-Gehäuse	TO-3P
Verlustleistung (max)	190W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	61A (Tc)
Rds On (Max) @ Id, Vgs	26 mOhm @ 30.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	98nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2730pF @ 25V
Verpackung	Tube



















































FQA55N10 ist neu im Original, Suche FQA55N10 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQA55N10 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQA55N10: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQA48N20 Fairchild/ON Semiconductor MOSFET N-CH 200V 48A TO-3P</p>	 <p>FQA55N25 AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 55A TO-3P</p>	 <p>FQA48N20 AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 48A TO-3P</p>	 <p>FQA55N10 AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 61A TO-3P</p>
 <p>FQA50N06 FAIRCHI FAIRCHI TO-220</p>	 <p>FQA47P06 AMI Semiconductor / ON Semiconductor MOSFET P-CH 60V 55A TO-3PN</p>	 <p>FQA59N30 FAIRCHILD FAIRCHILD TO-3P</p>	 <p>FQA47P06 Fairchild/ON Semiconductor MOSFET P-CH 60V 55A TO-3PN</p>

heiße Teile

Mehr

 FQA36P15	 FQA36P15_F109	 FQA36P15_F109	 FQA38N30	 FQA38N30
 FQA40N25	 FQA40N25	 FQA40N30	 FQA40N50	 FQA40N50L
 FQA44N10	 FQA44N10	 FQA44N30	 FQA44N30	 FQA46N15
 FQA46N15	 FQA46N15_F109	 FQA46N15_F109	 FQA46P06	 FQA46P15
 FQA47P06	 FQA47P06	 FQA48N20	 FQA48N20	 FQA55N10
 FQA55N25	 FQA55N25	 FQA62N25C	 FQA62N25C	 FQA65N06
 FQA65N06	 FQA65N20	 FQA65N20	 FQA6N90C	 FQA70N10
 FQA70N10	 FQA70N15	 FQA70N15	 FQA7N80C	 FQA7N80C
 FQA8N100C	 FQA8N100C	 FQA8N80C	 FQA8N80C	 FQA90N08
 FQA90N08	 FQA90N10V2	 FQA90N10V2	 FQA90N15	 FQA90N15

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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